



DMT6030LFDF

60V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
60V	$25.5m\Omega$ @ $V_{GS} = 10V$	6.8A
000	$35m\Omega @ V_{GS} = 4.5V$	5.7A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

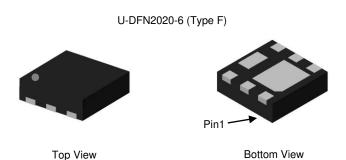
- Load Switch
- Adaptor Switch
- Notebook PC

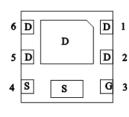
Features and Benefits

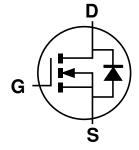
- 100% Unclamped Inductive Switch (UIS) Test in Production— Ensures More Reliable and Robust End Application
- 0.6mm Profile –Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (24)
- Weight: 0.007 grams (Approximate)







Pin Out Bottom View

Equivalent Circuit

Ordering Information (Note 4)

Part Number	Package	Quantity per Reel
DMT6030LFDF-7	U-DFN2020-6 (Type F)	3,000
DMT6030LFDF-13	U-DFN2020-6 (Type F)	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



Marking Information

Site1:

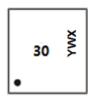


30 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Year	2017	20	18	2019	2020	20	21	2022	2023	20	24	2025
Code	E	F		G	Н			J	K		L	М
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Site2:



30 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 9 = 2019) W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	7	8	9	0	1	2	3	4	5

Week	1-26	27-52	53
Code	A-Z	a-z	Z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	T	U	V	W	X	Υ	Z



Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V_{DSS}	60	V
Gate-Source Voltage	V_{GSS}	±20	V		
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	I _D	6.8 5.4	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%))		I _{DM}	40	Α
Maximum Body Diode Continuous Current			I _S	6.8	Α
Pulsed Body Diode Forward Current (10µs Pulse, D	I _{SM}	40	Α		
Avalanche Current (Note 7) L = 0.1mH	I _{AS}	14.7	Α		
Avalanche Energy (Note 7) L = 0.1mH			E _{AS}	10.8	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25$ °C	P _D	0.86	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{OJA}	146	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	P _D	1.76	W
Thermal Resistance, Junction to Ambient (Note 6)		R _{OJA}	71	°C/W
Total Power Dissipation (Note 6)	$T_C = +25^{\circ}C$	P_{D}	9.62	W
Thermal Resistance, Junction to Case (Note 6)		R _{eJC}	13	°C/W
Operating and Storage Temperature Range	•	$T_{J_i}T_{STG}$	-55 to +150	°C

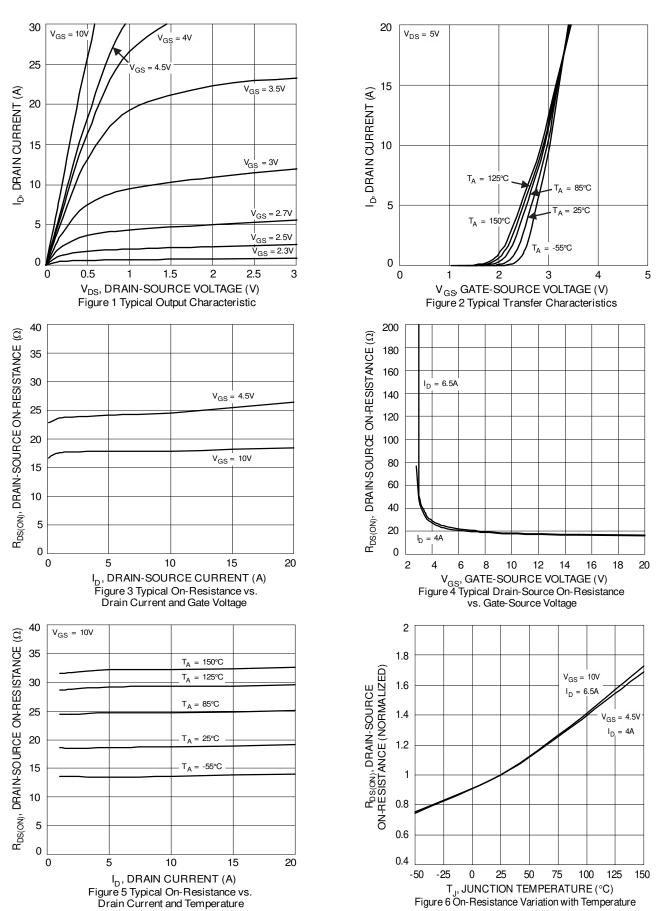
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Syllibol	IVIIII	Тур	IVIAX	Ullit	rest Condition	
Drain-Source Breakdown Voltage	BV _{DSS}	60			V	V _{GS} = 0V, I _D = 250μA	
Zero Gate Voltage Drain Current		_		1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{DSS}		_	±100	nΑ		
ON CHARACTERISTICS (Note 8)	I _{GSS}	_		±100	IIA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
,	1 1/	4	I	0.5	V	V V I 050A	
Gate Threshold Voltage	V _{GS(TH)}	I		2.5	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		18.3	25.5	mΩ	$V_{GS} = 10V, I_D = 6.5A$	
	1.103(014)		24.8	35		$V_{GS} = 4.5V, I_D = 4A$	
Diode Forward Voltage	V_{SD}		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	639			.,	
Output Capacitance	Coss	_	166	_	рF	$V_{DS} = 30V$, $V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	C _{RSS}	_	13.1	_		1 – 11011 12	
Gate Resistance	R _G	_	1.39	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Q_{G}	_	9.1	_			
Total Gate Charge (V _{GS} = 4.5V)	Q_{G}	_	4.5	_	nC	Vps = 30V. lp = 10A	
Gate-Source Charge	Q_{GS}	_	1.2	_	110	VDS = 30 V, ID = 10A	
Gate-Drain Charge	Q_{GD}	_	2.0	_			
Turn-On Delay Time	t _{D(ON)}	_	2.6	_			
Turn-On Rise Time	t _R	_	2.2	_	ns	$V_{GS} = 10V, V_{DD} = 30V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	10.7	_	ns	$R_G = 6\Omega$, $I_D = 10A$	
Turn-Off Fall Time	t _F	_	3.4	_			
Body Diode Reverse Recovery Time	t _{RR}	_	26.5	_	ns	1 100 41/44 1000/	
Body Diode Reverse Recovery Charge	Q _{RR}	_	12.3		nC	$I_S = 10A$, di/dt = 100A/ μ s	

Notes:

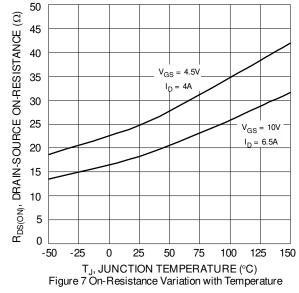
- 5. Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.
- 6. Device mounted on FR-4 substrate PCB, 2oz copper, with 1inch square copper plate.
- 7. IAS and EAS ratings are based on low frequency and duty cycles to keep $T_J = +25$ °C.
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to product testing.

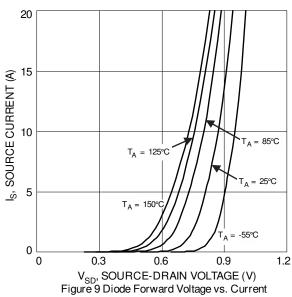


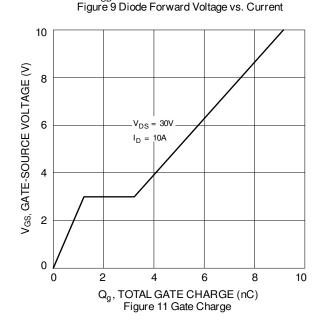












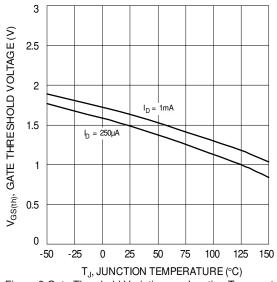
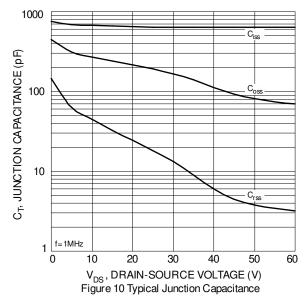
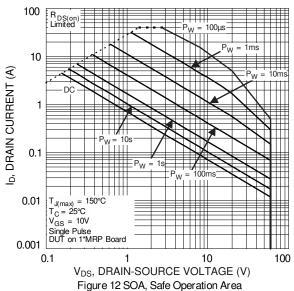
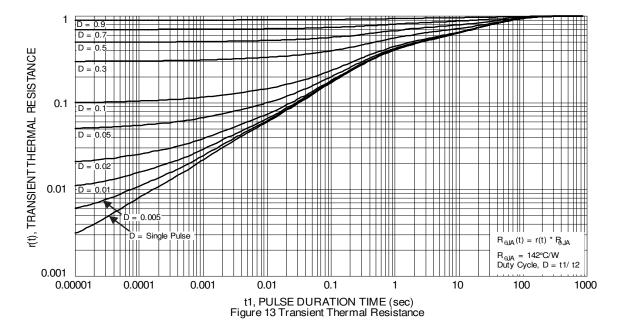


Figure 8 Gate Threshold Variation vs. Junction Temperature







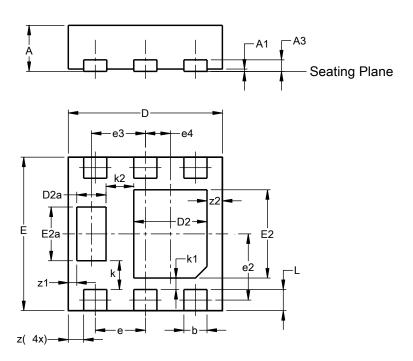




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)

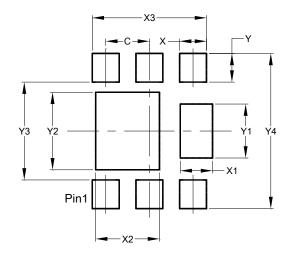


U-DFN2020-6									
	(Type F)								
Dim	Min	Min Max Typ							
Α	0.57	0.63	0.60						
A 1	0.00	0.05	0.03						
А3	-	-	0.15						
b	0.25	0.35	0.30						
D	1.95	2.05	2.00						
D2	0.85	1.05	0.95						
D2a	0.33	0.43	0.38						
Е	1.95	2.05	2.00						
E2	1.05	1.25	1.15						
E2a	0.65	0.75	0.70						
е		0.65 BS	С						
e2	C).863 BS	SC						
е3		0.70 BS	С						
e4).325 BS							
k		0.37 BS	С						
k1		0.15 BSC							
k2		0.36 BS	С						
L		0.325							
Z		0.20 BS							
z 1	0.110 BSC								
z2		0.20 BS	С						
All C	imens	ions in	mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value
Dillicusions	(in mm)
С	0.650
X	0.400
X1	0.480
X2	0.950
Х3	1.700
Υ	0.425
Y1	0.800
Y2	1.150
Y3	1.450
V4	2 300



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